

**MULTIPLE RS-232 DRIVERS AND RECEIVERS****AZ75232****General Description**

The AZ75232 combines three drivers and five receivers, which conform to the EIA/TIA-232-F and ITU v.28 standards. Each receiver converts EIA/TIA-232-F inputs to 5-V TTL/CMOS levels and each driver converts TTL/CMOS input levels into EIA/TIA-232-F levels.

The flow-through pinout facilitates simple non-cross-over board layout. The AZ75232 provides a one-chip solution for the common 9-pin serial RS-232 interface between data terminal and data communications equipment.

The AZ75232 is available in SOIC-20, SSOP-20 and TSSOP-20 packages.

Features

- Single Chip with Easy Interface between UART and Serial-Port Connector
- Meet the Requirement of EIA/TIA-232-F and ITU v.28 Standards
- Designed to Support Data Rates up to 120kbit/s
- 3 Drivers and 5 Receivers
- Flow-through Pinout

Applications

- Mother Board
- Peripheral Equipment



Figure 1. Package Types of AZ75232

**MULTIPLE RS-232 DRIVERS AND RECEIVERS****AZ75232****Pin Configuration**

M/GS/G Package
(SOIC-20/SSOP-20/TSSOP-20)

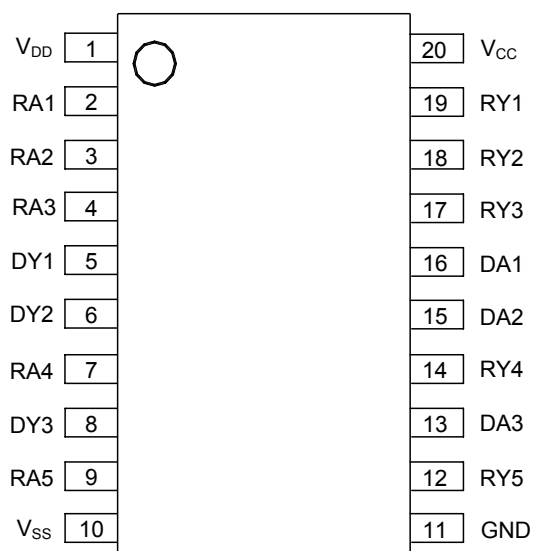


Figure 2. Pin Configuration of AZ75232 (Top View)

Pin Description

Pin Number	Pin Name	Function	Pin Number	Pin Name	Function
1	V _{DD}	Positive Supply Voltage for Driver	11	GND	Ground
2	RA1	Receiver Input	12	RY5	Receiver Output
3	RA2	Receiver Input	13	DA3	Driver Input
4	RA3	Receiver Input	14	RY4	Receiver Output
5	DY1	Driver Output	15	DA2	Driver Input
6	DY2	Driver Output	16	DA1	Driver Input
7	RA4	Receiver Input	17	RY3	Receiver Output
8	DY3	Driver Output	18	RY2	Receiver Output
9	RA5	Receiver Input	19	RY1	Receiver Output
10	V _{SS}	Negative Supply Voltage for Driver	20	V _{CC}	Supply Voltage for Receiver



MULTIPLE RS-232 DRIVERS AND RECEIVERS

AZ75232

Functional Block Diagram

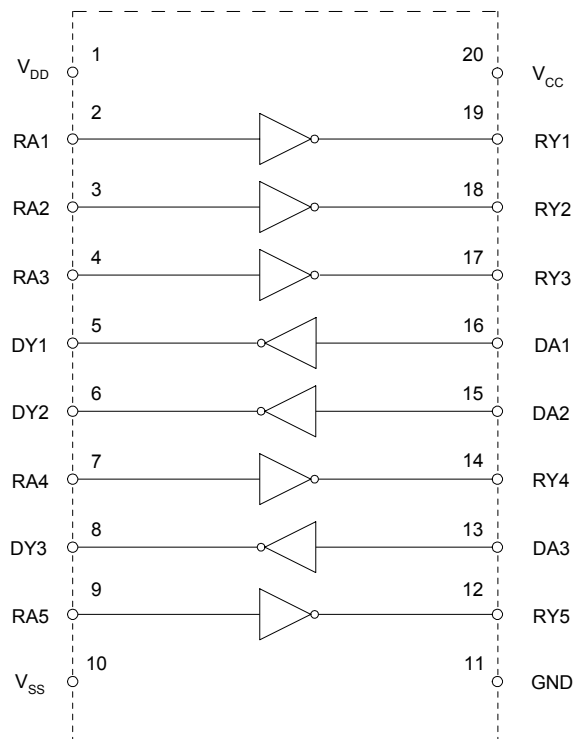
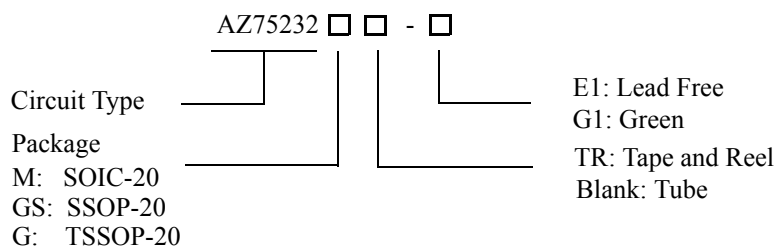


Figure 3. Functional Block Diagram of AZ75232

Ordering Information



Package	Temperature Range	Part Number		Marking ID		Packing Type
		Lead Free	Green	Lead Free	Green	
SOIC-20	-40 to 85°C	AZ75232M-E1	AZ75232M-G1	AZ75232M-E1	AZ75232M-G1	Tube
		AZ75232MTR-E1	AZ75232MTR-G1	AZ75232M-E1	AZ75232M-G1	Tape & Reel
SSOP-20	-40 to 85°C	AZ75232GS-E1	AZ75232GS-G1	AZ75232GS-E1	AZ75232GS-G1	Tube
		AZ75232GSTR-E1	AZ75232GSTR-G1	AZ75232GS-E1	AZ75232GS-G1	Tape & Reel
TSSOP-20	-40 to 85°C	AZ75232G-E1	AZ75232G-G1	232GE	232GG	Tube
		AZ75232GTR-E1	AZ75232GTR-G1	232GE	232GG	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.



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Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Value		Unit
Supply Voltage	V _{DD}	15		V
	V _{SS}	-15		
	V _{CC}	7		
Input Voltage Range	V _I	Driver	-15 to 7	V
		Receiver	-30 to 30	
Power Dissipation (T _A =25°C)	P _D	SOIC-20	1340	mW
		SSOP-20	1210	
		TSSOP-20	1100	
Driver Output Voltage Range	V _O	-15 to 15		V
Receiver Low-Level Output Current	I _{OL}	20		mA
Operating Junction Temperature	T _J	150		°C
Storage Temperature Range	T _{STG}	-65 to 150		°C
Lead Temperature (Soldering, 10sec)	T _{LEAD}	260		°C

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter		Symbol	Min	Max	Unit
Supply Voltage		V_{DD}	7.5	15	V
		V_{SS}	-15	-7.5	
		V_{CC}	4.5	5.5	
High-Level Input Voltage (Driver Only)		V_{IH}	1.9		V
Low-Level Input Voltage (Driver Only)		V_{IL}		0.8	V
High-Level Output Current	Driver	I_{OH}		-6	mA
	Receiver			-0.5	
Low-Level Output Current	Driver	I_{OL}		6	mA
	Receiver			16	
Operating Temperature Range		T_A	-40	85	$^{\circ}\text{C}$



MULTIPLE RS-232 DRIVERS AND RECEIVERS

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Electrical Characteristics

($T_A=25^{\circ}\text{C}$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
VOLTAGE SUPPLY SECTION ($V_{CC}=5\text{V}$, $V_{DD}=9\text{V}$, $V_{SS}=-9\text{V}$, unless otherwise specified)						
Supply Current from V_{DD}	I_{DD}	All inputs at 1.9V, no load	$V_{DD}=9\text{V}$, $V_{SS}=-9\text{V}$		15	mA
			$V_{DD}=12\text{V}$, $V_{SS}=-12\text{V}$		19	
			$V_{DD}=15\text{V}$, $V_{SS}=-15\text{V}$		25	
		All inputs at 0.8V, no load	$V_{DD}=9\text{V}$, $V_{SS}=-9\text{V}$		4.5	
			$V_{DD}=12\text{V}$, $V_{SS}=-12\text{V}$		5.5	
			$V_{DD}=15\text{V}$, $V_{SS}=-15\text{V}$		9	
Supply Current from V_{SS}	I_{SS}	All inputs at 1.9V, no load	$V_{DD}=9\text{V}$, $V_{SS}=-9\text{V}$		-15	mA
			$V_{DD}=12\text{V}$, $V_{SS}=-12\text{V}$		-19	
			$V_{DD}=15\text{V}$, $V_{SS}=-15\text{V}$		-25	
		All inputs at 0.8V, no load	$V_{DD}=9\text{V}$, $V_{SS}=-9\text{V}$		-3.2	
			$V_{DD}=12\text{V}$, $V_{SS}=-12\text{V}$		-3.2	
			$V_{DD}=15\text{V}$, $V_{SS}=-15\text{V}$		-3.2	
Supply Current from V_{CC}	I_{CC}	All inputs at 5V, no load, $V_{CC}=5\text{V}$			30	mA
DRIVER SECTION ($V_{CC}=5\text{V}$, $V_{DD}=9\text{V}$, $V_{SS}=-9\text{V}$, unless otherwise specified)						
High-Level Output Voltage	V_{OH}	$V_{IL}=0.8\text{V}$, $R_L=3\text{k}\Omega$	6	7.5		V
Low-Level Output Voltage	V_{OL}	$V_{IH}=1.9\text{V}$, $R_L=3\text{k}\Omega$		-7.5	-6	V
High-Level Input Current	I_{IH}	$V_I=5\text{V}$			10	μA
Low-Level Input Current	I_{IL}	$V_I=0\text{V}$			-1.6	mA
High-Level Short-Circuit Output Current	$I_{OS(H)}$	$V_{IL}=0.8\text{V}$, $V_O=0\text{V}$	-4.5	-12	-19.5	mA
Low-Level Short-Circuit Output Current	$I_{OS(L)}$	$V_{IH}=2\text{V}$, $V_O=0\text{V}$	4.5	12	19.5	mA
Output Resistance	r_O	$V_{CC}=V_{DD}=V_{SS}=0$, $V_O=-2\text{V}$ to 2V	300			Ω
DRIVER SECTION ($V_{CC}=5\text{V}$, $V_{DD}=12\text{V}$, $V_{SS}=-12\text{V}$, unless otherwise specified)						
Propagation Delay Time Low to High Level Output	t_{PLH}	$R_L=3\text{k}\Omega$ to $7\text{k}\Omega$, $C_L=15\text{pF}$		315	500	ns
Propagation Delay Time High to Low Level Output	t_{PHL}	$R_L=3\text{k}\Omega$ to $7\text{k}\Omega$, $C_L=15\text{pF}$		75	175	ns
Transition Time Low to High Level Output	t_{TLH}	$R_L=3\text{k}\Omega$ to $7\text{k}\Omega$	$C_L=15\text{pF}$	60	100	ns
			$C_L=2500\text{pF}$ (Note 2)	1.7	2.5	μs
Transition Time High to Low Level Output	t_{THL}	$R_L=3\text{k}\Omega$ to $7\text{k}\Omega$	$C_L=15\text{pF}$	40	75	ns
			$C_L=2500\text{pF}$ (Note 2)	1.5	2.5	μs


MULTIPLE RS-232 DRIVERS AND RECEIVERS
AZ75232
Electrical Characteristics (Continued)

(T_A=25°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
RECEIVER SECTION (V_{CC}=5V, V_{DD}=9V, V_{SS}=-9V, unless otherwise specified)						
Positive-Going Input Threshold Voltage	V _{IT+}		1.75	1.9	2.3	V
		T _A = -40 to 85 °C	1.55		2.3	V
Negative-Going Input Threshold Voltage	V _{IT-}		0.75	0.97	1.25	V
Input Hysteresis Voltage	V _{HYS}		0.5			V
High-Level Output Voltage	V _{OH}	I _{OH} =-0.5mA	2.6	4	5	V
		V _{IH} =0.75V Input Open	2.6			
Low-Level Output Voltage	V _{OL}	I _{OL} =10mA, V _I =3V		0.2	0.45	V
High-Level Input Current	I _{IH}	V _I =25V	3.6		8.3	mA
		V _I =3V	0.43			
Low-Level Input Current	I _{IL}	V _I =-25V	-3.6		-8.3	mA
		V _I =-3V	-0.43			
Short-Circuit Output Current	I _{OS}	V _I =0.8V		-3.4	-12	mA
RECEIVER SECTION (V_{CC}=5V, V_{DD}=12V, V_{SS}=-12V, unless otherwise specified)						
Propagation Delay Time Low to High Level Output	t _{PLH}	R _L =5kΩ, C _L =50pF		105	250	ns
		R _L =1.5kΩ, C _L =15pF		100	160	
Propagation Delay Time High to Low Level Output	t _{PHL}	R _L =5kΩ, C _L =50pF		60	150	ns
		R _L =1.5kΩ, C _L =15pF		42	100	
Transition Time Low to High Level Output	t _{TLH}	R _L =5kΩ, C _L =50pF		170	350	ns
		R _L =1.5kΩ, C _L =15pF		90	175	
Transition Time High to Low Level Output	t _{THL}	R _L =5kΩ, C _L =50pF		16	60	ns
		R _L =1.5kΩ, C _L =15pF		15	50	

Note 2: Measured between -3V and 3V points of the output waveform (EIA/TIA-232-F conditions); all unused inputs are tied either high or low.



Typical Performance Characteristics

Driver Section

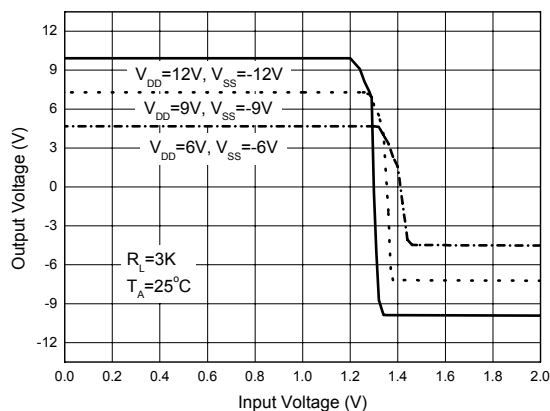


Figure 4. Voltage Transfer Characteristics

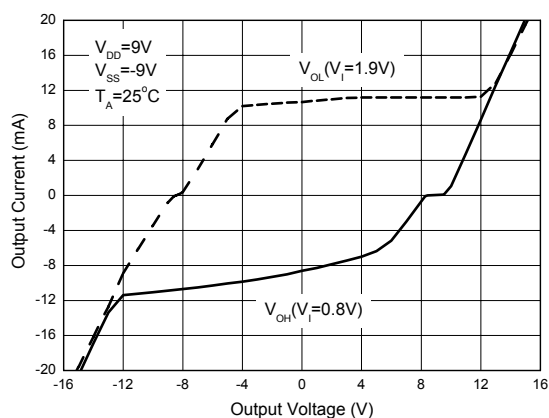


Figure 5. Output Current vs. Output Voltage

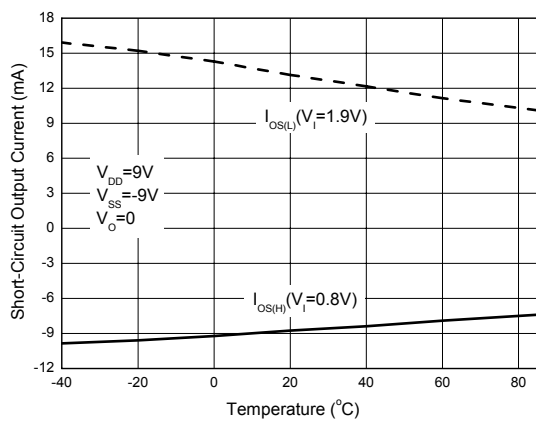


Figure 6. Short-Circuit Output Current vs. Temperature

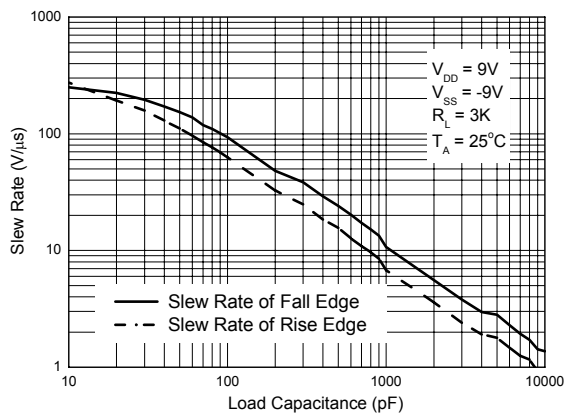


Figure 7. Slew Rate vs. Load Capacitance



Typical Performance Characteristics (Continued)

Receiver Section

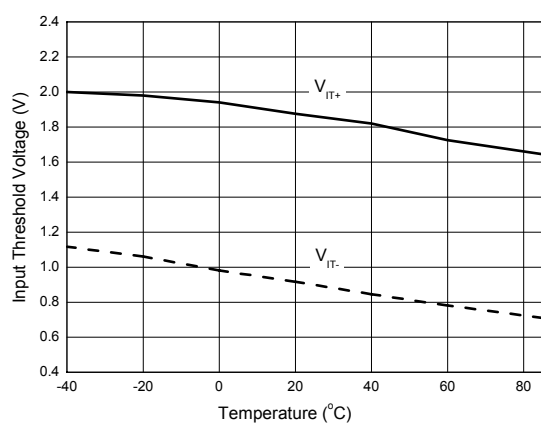


Figure 8. Input Threshold Voltage vs. Temperature

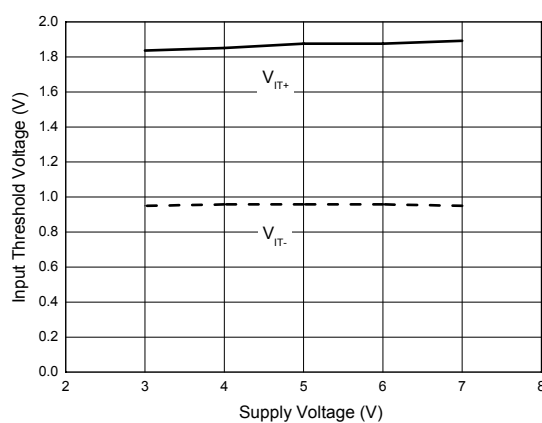


Figure 9. Input Threshold Voltage vs. Supply Voltage

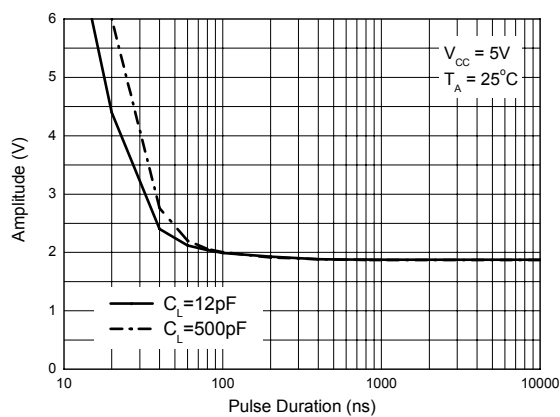


Figure 10. Noise Rejection

Typical Application

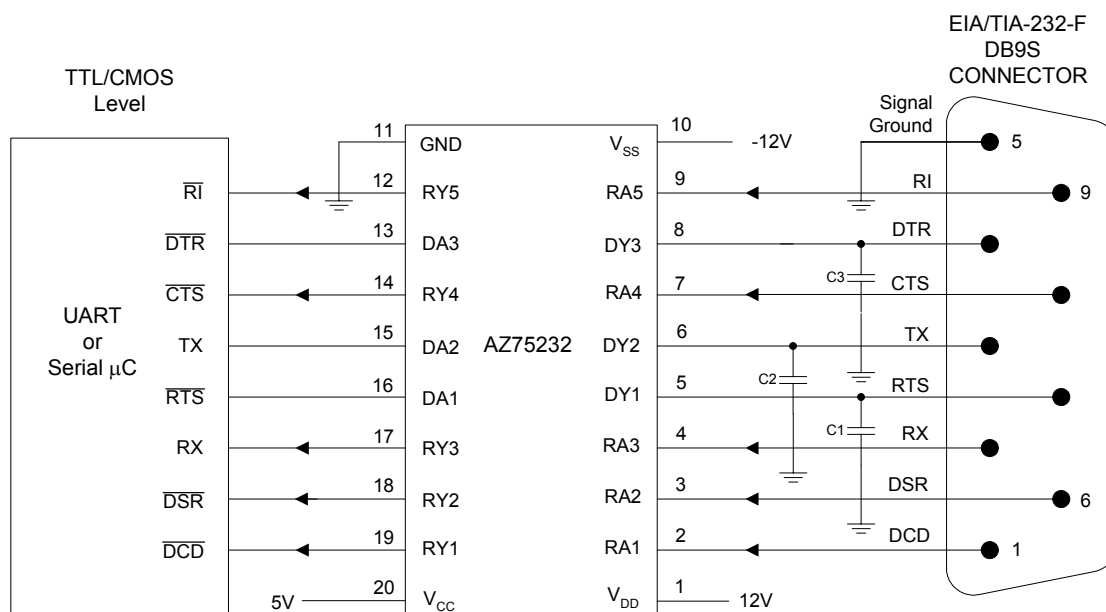
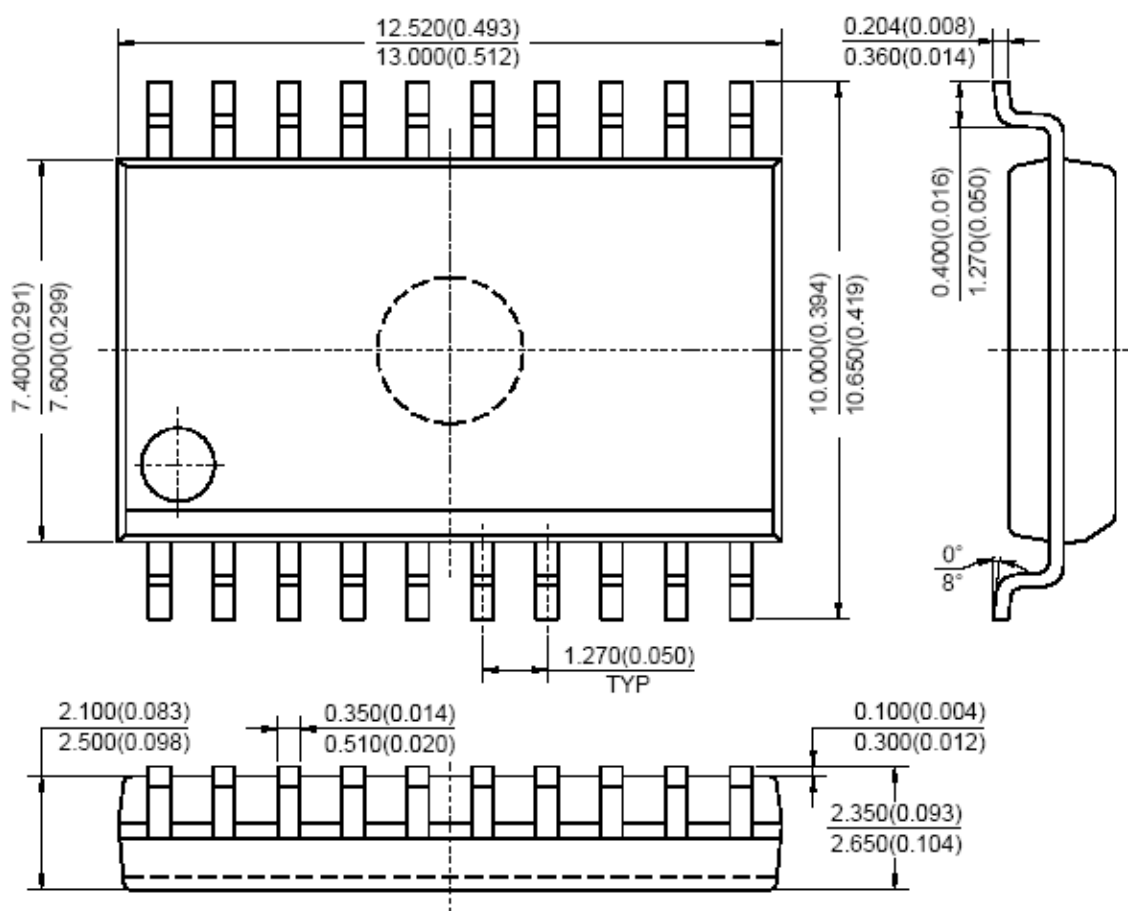
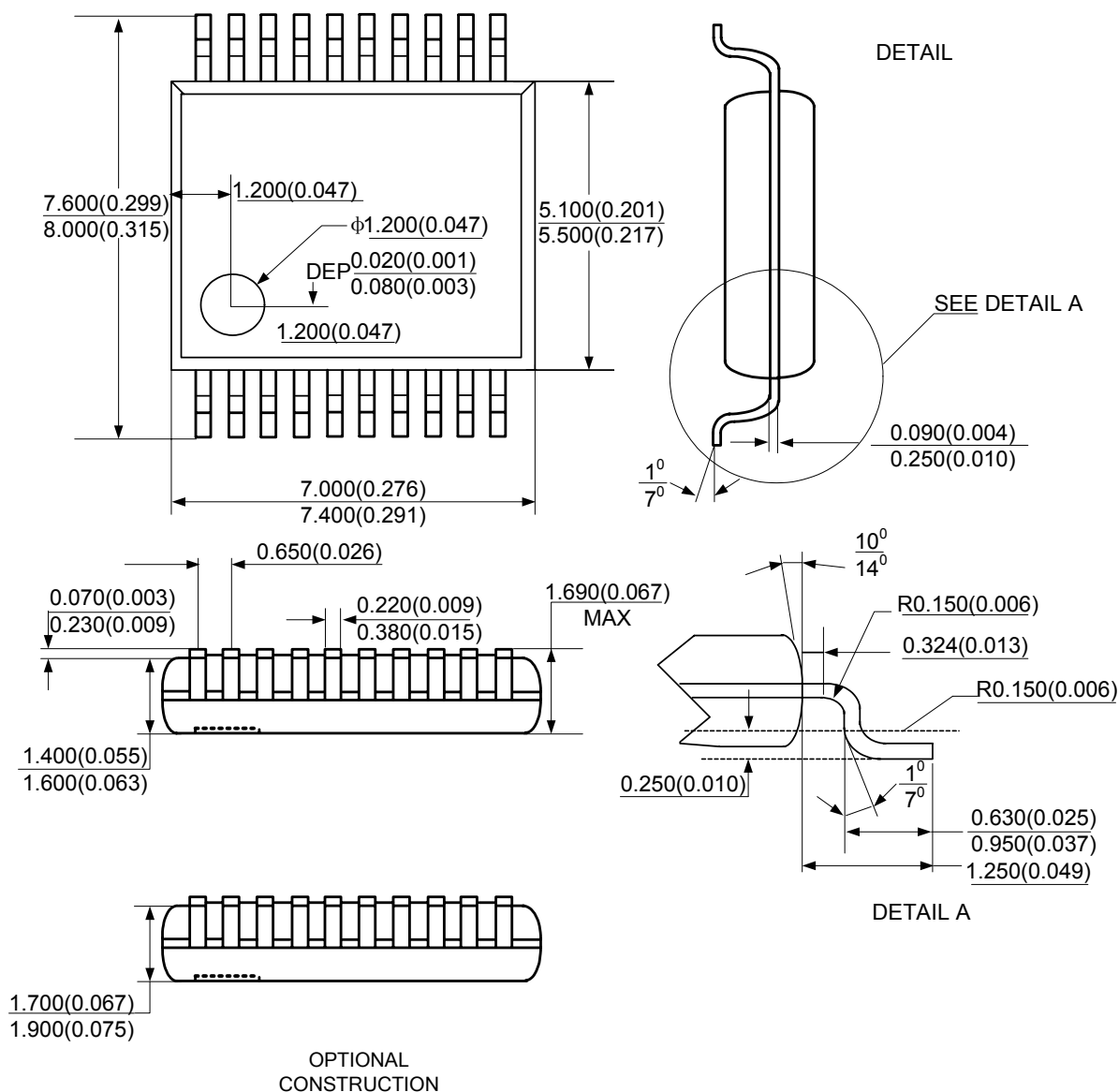


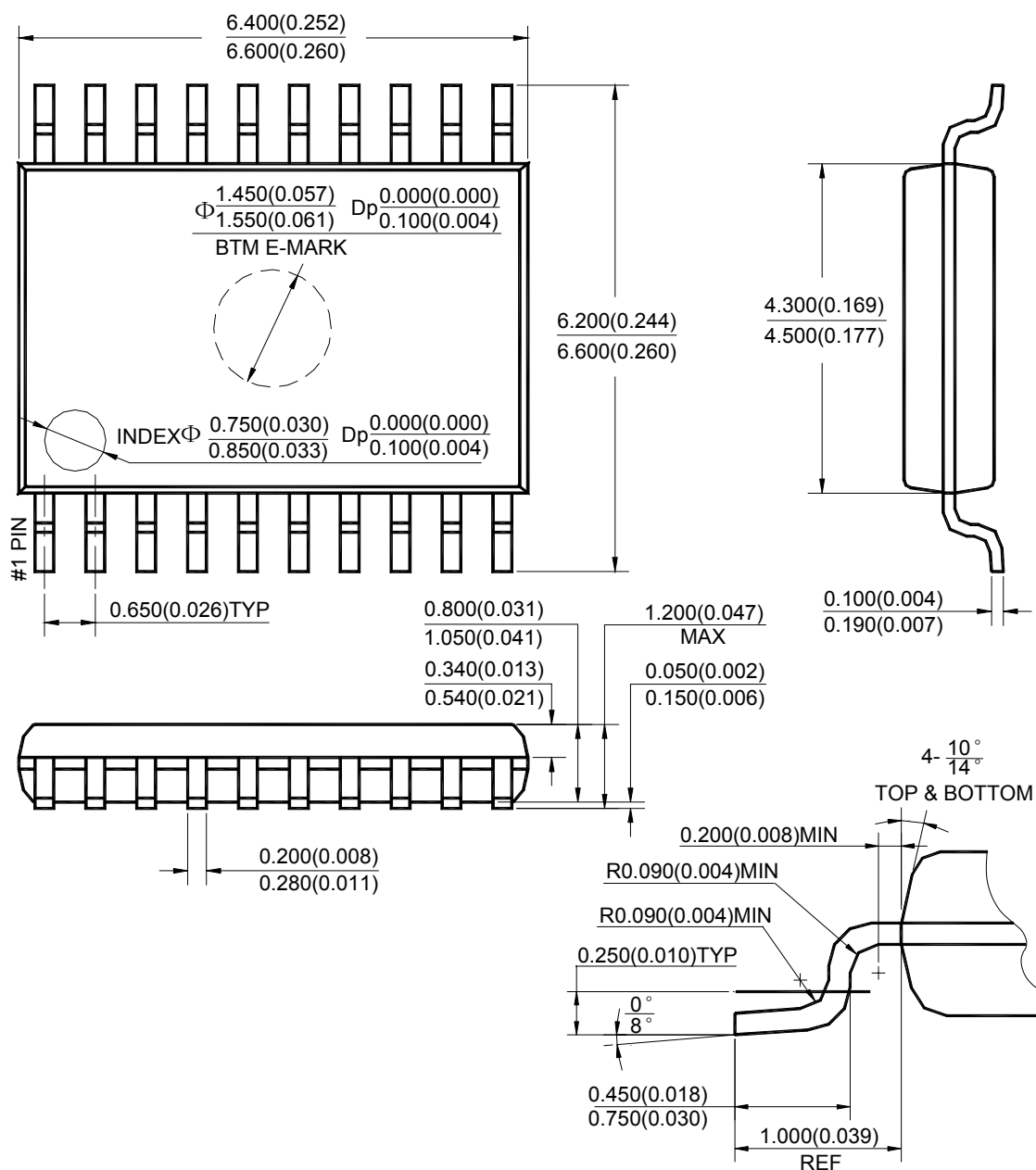
Figure 11. Typical Application of AZ75232

**MULTIPLE RS-232 DRIVERS AND RECEIVERS****AZ75232****Mechanical Dimensions****SOIC-20****Unit: mm(inch)**

Note: Eject hole, oriented hole and mold mark is optional.

**MULTIPLE RS-232 DRIVERS AND RECEIVERS****AZ75232****Mechanical Dimensions (Continued)****SSOP-20****Unit: mm(inch)**

Note: Eject hole, oriented hole and mold mark is optional

**MULTIPLE RS-232 DRIVERS AND RECEIVERS****AZ75232****Mechanical Dimensions****TSSOP-20****Unit: mm(inch)**

Note: Eject hole, oriented hole and mold mark is optional.



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